BY329 series

GENERAL DESCRIPTION

Glass-passivated double diffused rectifier diodes in a plastic envelope featuring low forward voltage drop, fast reverse recovery and soft recovery characteristic. The devices are intended for use in TV receivers, monitors and switched mode power supplies.

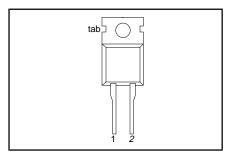
QUICK REFERENCE DATA

SYMBOL	PARAMETER	MAX.	MAX.	MAX.	UNIT
	BY329	-800	-1000	-1200	
V_{RRM}	Repetitive peak reverse voltage	800	1000	1200	V
I _{F(AV)}	Average forward current	8	8	8	Α
I _{FSM}	Non-repetitive peak forward current	75	75	75	Α
t _{rr}	Reverse recovery time	135	135	135	ns

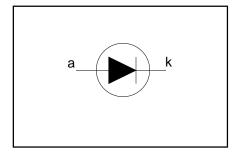
PINNING - TO220AC

PIN	DESCRIPTION
1	cathode (k)
2	anode (a)
tab	cathode (k)

PIN CONFIGURATION



SYMBOL



LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.		UNIT	
V _{RSM}	Non-repetitive peak reverse voltage		-	-800 800	-1000 1000	-1200 1200	V
$egin{array}{c} V_{RRM} \ V_{RWM} \end{array}$	Repetitive peak reverse voltage Crest working reverse voltage		- -	800 600	1000 800	1200 1000	V V
I _{F(AV)}	Average forward current ¹	square wave; $\delta = 0.5$; $T_{mb} \le 122 ^{\circ}C$	-		8		Α
		sinusoidal; a = 1.57; $T_{mb} \le 125 ^{\circ}C$	-		7		Α
I _{F(RMS)}	RMS forward current	2	-		11		Α
I _{FRM}	Repetitive peak forward current	t = 25 μs; δ = 0.5; $T_{mb} \le$ 122 °C	-		16		Α
I _{FSM}	Non-repetitive peak forward	t = 10 ms	-		75		Α
1 0.00	current.	t = 8.3 ms sinusoidal; T _j = 150 °C prior to surge; with reapplied V _{RWM(max)}	-		82		А
l ² t	I ² t for fusing	t = 10 ms	_		28		A ² s
T _{stg}	Storage temperature		-40		150		,C
T_{j}^{sig}	Operating junction temperature		-		150		°Č

October 1994 1 Rev 1.100

¹ Neglecting switching and reverse current losses.

BY329 series

THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
R _{th j-mb}	Thermal resistance junction to mounting base		-	-	2.0	K/W
R _{th j-a}		in free air.	-	60	-	K/W

STATIC CHARACTERISTICS

 $T_j = 25$ °C unless otherwise stated

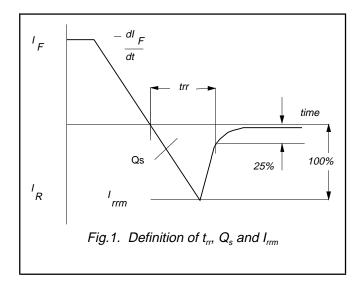
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V _F	Forward voltage	$I_F = 20 \text{ A}$	-	1.5	1.85	V
I _R	Reverse current	$V_R = V_{RWM}$; $T_i = 125 \text{ °C}$		0.1	1.0	mA

DYNAMIC CHARACTERISTICS

 $T_i = 25$ °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$\begin{matrix} t_{rr} \\ Q_s \\ dI_R/dt \end{matrix}$	Reverse recovery charge	$\begin{array}{l} I_F = 1 \text{ A; } V_R \geq 30 \text{ V; } -dI_F/dt = 50 \text{ A/}\mu\text{s} \\ I_F = 2 \text{ A; } V_R \geq 30 \text{ V; } -dI_F/dt = 20 \text{ A/}\mu\text{s} \\ I_F = 2 \text{ A; } -dI_F/dt = 20 \text{ A/}\mu\text{s} \end{array}$		100 0.5 50	135 0.7 60	ns μC A/μs

BY329 series



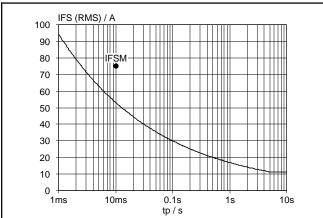


Fig.4. Maximum non-repetitive rms forward current. $I_F = f(t_p)$; sinusoidal current waveform; $T_j = 150^{\circ}\text{C}$ prior to surge with reapplied V_{RWM} .

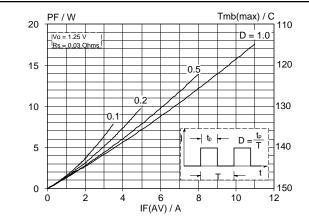


Fig.2. Maximum forward dissipation, $P_F = f(I_{F(AV)})$; square wave current waveform; parameter D = duty cycle = t_p/T .

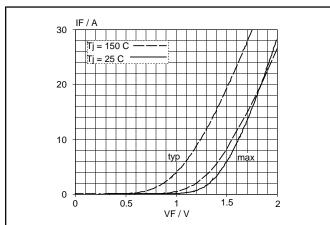


Fig.5. Typical and maximum forward characteristic; $I_F = f(V_F)$; parameter T_j

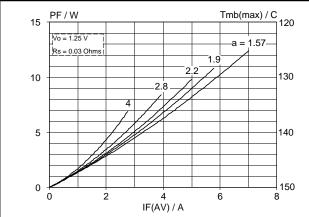
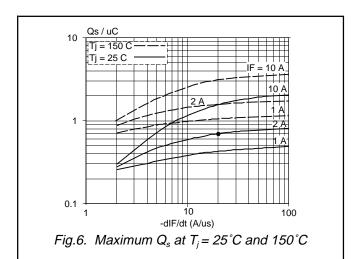


Fig.3. Maximum forward dissipation, $P_F = f(I_{F(AV)})$; sinusoidal current waveform; parameter a = form factor $= I_{F(RMS)}/I_{F(AV)}$.



BY329 series

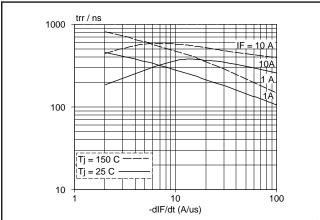
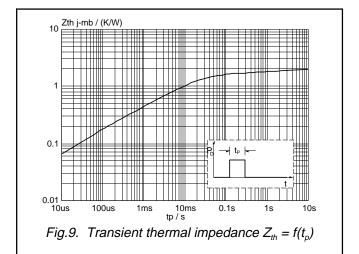


Fig.7. Maximum t_{rr} measured to 25% of I_{rrm} ; $T_j = 25^{\circ}C$ and 150°C



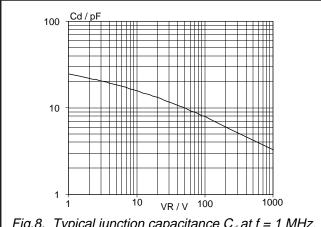
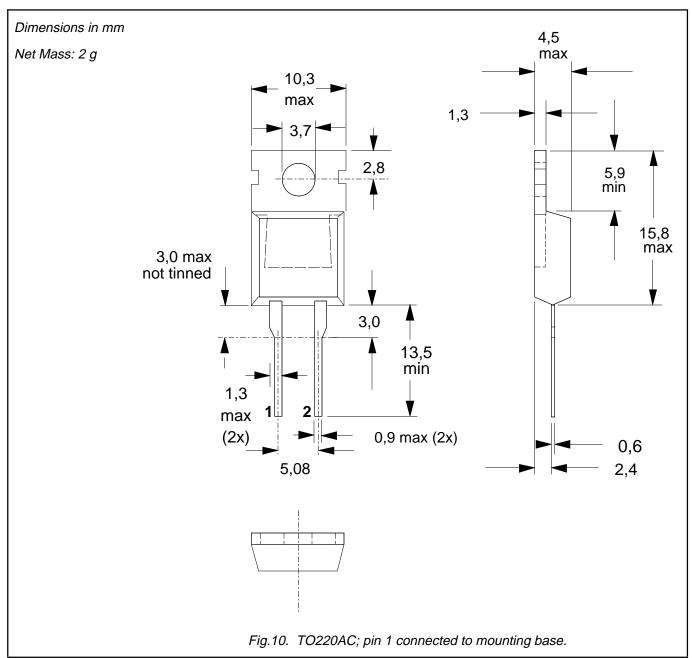


Fig.8. Typical junction capacitance C_d at f = 1 MHz, $T_j = 25^{\circ}C$

BY329 series

MECHANICAL DATA



- Accessories supplied on request: refer to mounting instructions for TO220 envelopes.
 Epoxy meets UL94 V0 at 1/8".

BY329 series

DEFINITIONS

Data sheet status					
Objective specification	This data sheet contains target or goal specifications for product development.				
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.				
Product specification This data sheet contains final product specifications.					

Limiting values

Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information

Where application information is given, it is advisory and does not form part of the specification.

© Philips Electronics N.V. 1994

All rights are reserved. Reproduction in whole or in part is prohibited without the prior written consent of the copyright owner.

The information presented in this document does not form part of any quotation or contract, it is believed to be accurate and reliable and may be changed without notice. No liability will be accepted by the publisher for any consequence of its use. Publication thereof does not convey nor imply any license under patent or other industrial or intellectual property rights.

LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices or systems where malfunction of these products can be reasonably expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.